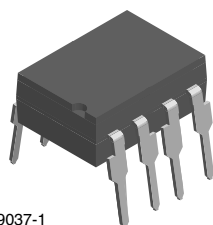
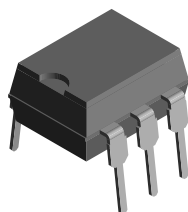
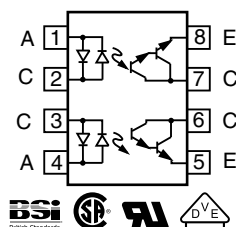
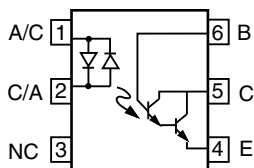


Optocoupler, Photodarlington Output, AC Input, High Gain (Single, Dual Channel)



i179037-1



FEATURES

- AC or polarity insensitive inputs
- Built-in reverse polarity input protection
- Industry standard DIP package
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


RoHS
COMPLIANT

APPLICATIONS

- Designed for applications requiring detection or monitoring of AC signals

AGENCY APPROVALS

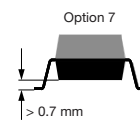
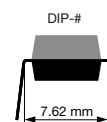
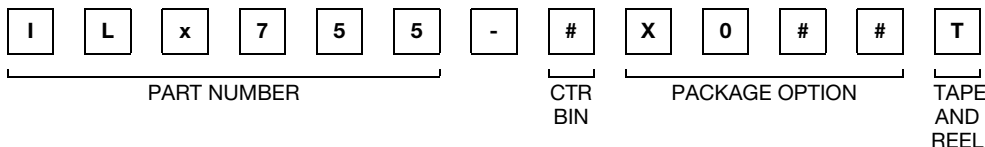
- UL1577, file no. E52744 system code H, double protection
- CSA 93751
- BSI IEC 60950; IEC 60065
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending), available with option 1
- CQC

DESCRIPTION

The IL755, ILD755 are bidirectional input optically coupled isolators. They consist of two gallium arsenide infrared emitting diodes coupled to a silicon NPN photodarlington per channel.

The IL755 is single channel Darlington optocoupler. The ILD755 has two isolated channels in a single DIP package.

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)			
	SINGLE CHANNEL, 6 PIN		DUAL CHANNEL, 8 PIN	
	± 2 mA	± 1 mA	± 2 mA	± 1 mA
UL, CSA, BSI, CQC	≥ 750	≥ 1000	≥ 750	≥ 1000
DIP-#	IL755-1	IL755-2	ILD755-1	ILD755-2
SMD-#, option 7	IL755-1X007T ⁽¹⁾	IL755-2X007T	-	ILD755-2X007T
VDE, UL, CSA, BSI, CQC	≥ 750	≥ 1000	≥ 750	≥ 1000
DIP-#	IL755-1X001	-	-	-
SMD-#, option 7	-	-	ILD755-1X017	-

Notes

- Additional options may be possible, please contact sales office.
- ⁽¹⁾ Also available in tubes; do not add "T" to end.



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
INPUT					
Forward continuous current			I _F	60	mA
Power dissipation			P _{diss}	100	mW
Derate linearly from 25°C				1.33	mW/°C
OUTPUT					
Collector emitter breakdown voltage			BV _{CEO}	60	V
Collector base breakdown voltage			BV _{CBO}	60	V
Power dissipation		IL755-1	P _{diss}	200	mW
		IL755-2		200	mW
		ILD755-1		150	mW
		ILD755-2		150	mW
Derate linearly from 25°C		IL755-1		2.6	mW/°C
		IL755-2		2.6	mW/°C
		ILD755-1		2.0	mW/°C
		ILD755-2		2.0	mW/°C
COUPLER					
Isolation test voltage between emitter and detector	t = 1 s		V _{ISO}	7500/5300	V _{AC peak} /V _{RMS}
Creepage distance				≥ 7	mm
Clearance distance				≥ 7	mm
Total power dissipation		IL755-1	P _{tot}	250	mW
		IL755-2		250	mW
		ILD755-1		400	mW
		ILD755-2		400	mW
Derate linearly from 25 °C		IL755-1		3.0	mW/°C
		IL755-2		3.0	mW/°C
		ILD755-1		3.0	mW/°C
		ILD755-2		3.0	mW/°C
Storage temperature			T _{stg}	- 55 to + 150	°C
Operating temperature			T _{amb}	- 55 to + 100	°C
Lead soldering time at 260 °C				10	s

Note

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = \pm 10\text{ mA}$	V_F		1.2	1.5	V
OUTPUT						
Collector emitter breakdown voltage	$I_C = 1.0\text{ mA}$	BV_{CEO}	60	75		V
Collector base breakdown voltage	$I_C = 10\text{ }\mu\text{A}$	BV_{CBO}	60	90		V
Collector emitter leakage current	$V_{CE} = 10\text{ V}, I_F = 0\text{ A}$	I_{CEO}		10	100	nA
COUPLER						
Collector emitter saturation voltage	$I_C = 10\text{ mA}, I_F = \pm 10\text{ mA}$	V_{CEsat}			1	V

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	$I_F = \pm 2\text{ mA}$, $V_{CE} = 5.0\text{ V}$	IL755-1	CTR	750			%
	$I_F = \pm 2\text{ mA}$, $V_{CE} = 5.0\text{ V}$	ILD755-1	CTR	750			%
	$I_F = \pm 1\text{ mA}$, $V_{CE} = 5.0\text{ V}$	IL755-2	CTR	1000			%
	$I_F = \pm 1\text{ mA}$, $V_{CE} = 5.0\text{ V}$	ILD755-2	CTR	1000			%

SWITCHING CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Rise time	$V_{CC} = 10\text{ V}$, $I_F = \pm 2\text{ mA}$, $R_L = 100\text{ }\Omega$	IL755-1	t_r		50		μs
		ILD755-1	t_r		50		μs
Fall time	$V_{CC} = 10\text{ V}$, $I_F = \pm 2\text{ mA}$, $R_L = 100\text{ }\Omega$	IL755-1	t_f		50		μs
		ILD755-1	t_f		50		μs
Rise time	$V_{CC} = 10\text{ V}$, $I_F = \pm 1\text{ mA}$, $R_L = 100\text{ }\Omega$	IL755-2	t_r		70		μs
		ILD755-2	t_r		70		μs
Fall time	$V_{CC} = 10\text{ V}$, $I_F = \pm 1\text{ mA}$, $R_L = 100\text{ }\Omega$	IL755-2	t_f		70		μs
		ILD755-2	t_f		70		μs

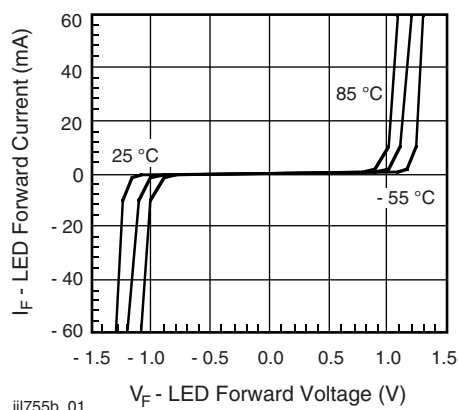
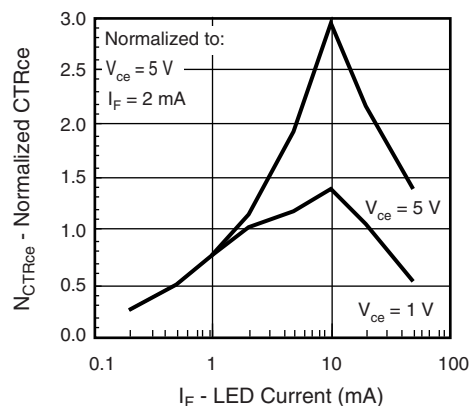
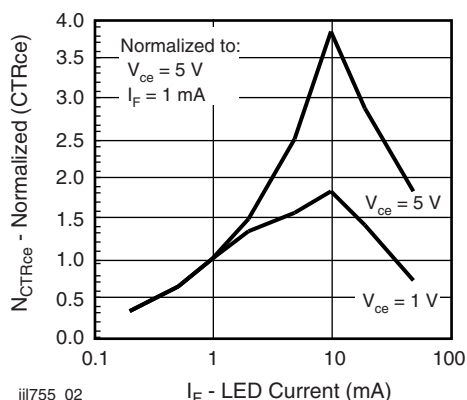
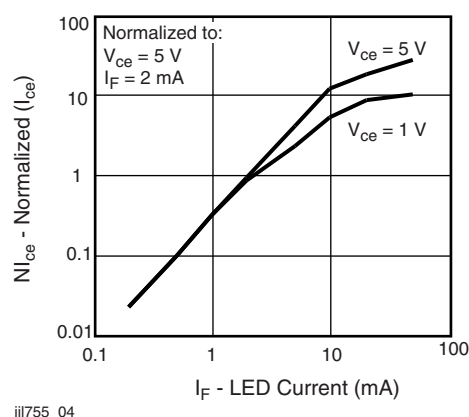
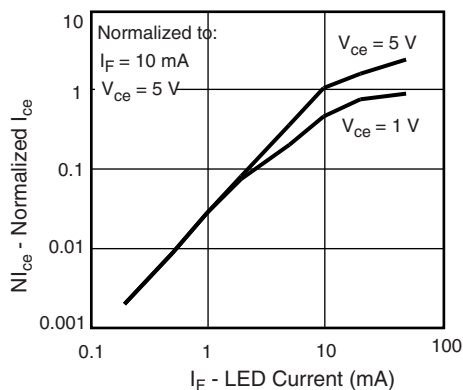
TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)


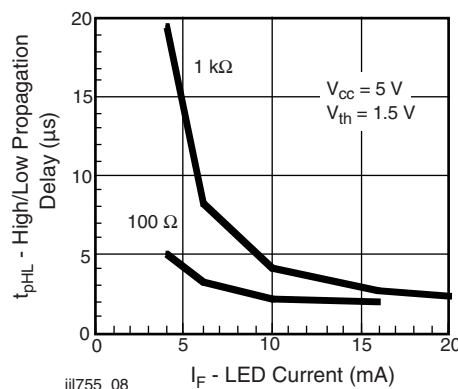
Fig. 1 - LED Forward Current vs. Forward Voltage


Fig. 3 - Normalized Non-Saturated and Saturated CTR_{CE} vs. LED Current

Fig. 2 - Normalized Non-Saturated and Saturated CTR_{CE} vs. LED Current

Fig. 4 - Normalized Non-Saturated and Saturated I_{CE} vs. LED Current



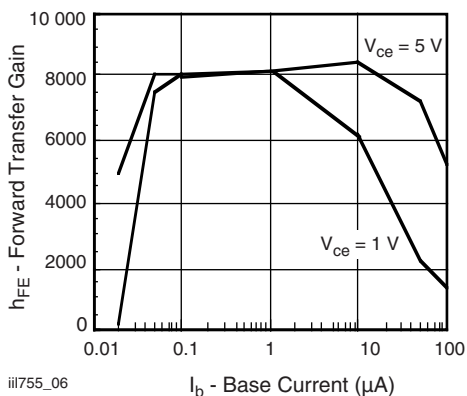
iii755_05

Fig. 5 - Normalized Non-Saturated and Saturated Collector-Emitter Current vs. LED Current

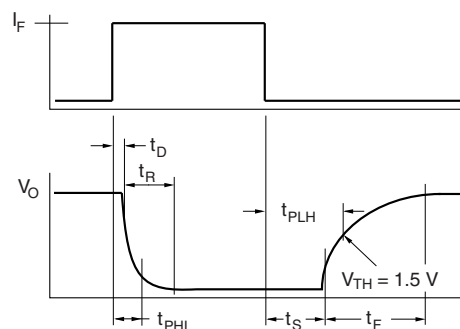


iii755_08

Fig. 8 - High to Low Propagation Delay vs. Collector Load Resistance and LED Current

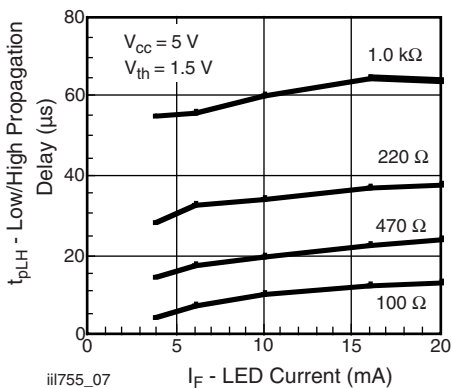


iii755_06

Fig. 6 - Non-Saturated and Saturated h_{FE} vs. Base Current


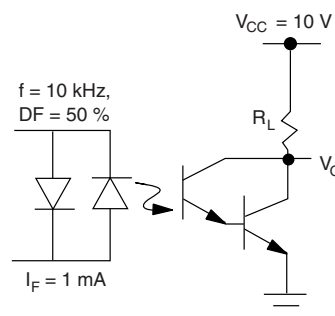
iii755_09

Fig. 9 - Switching Waveform



iii755_07

Fig. 7 - Low to High Propagation Delay vs. Collector Load Resistance and LED Current

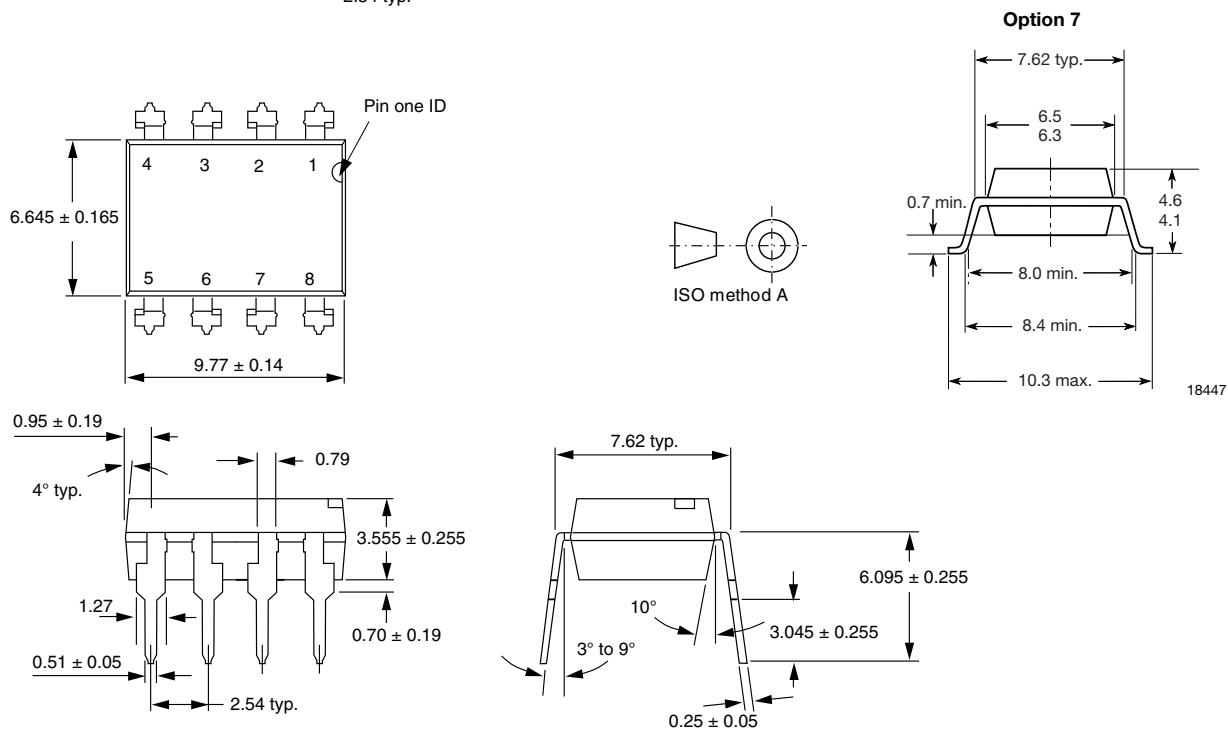
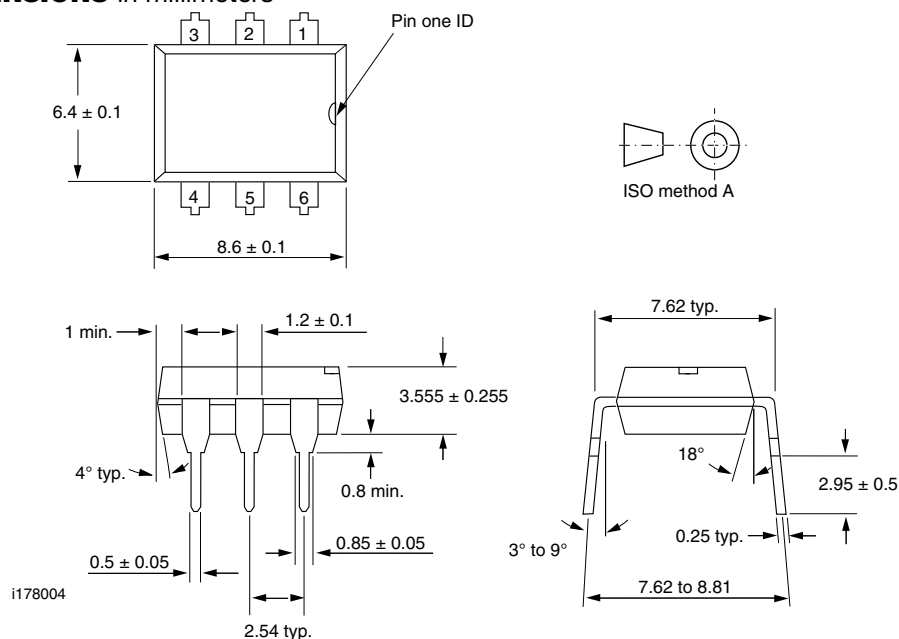


iii755_10

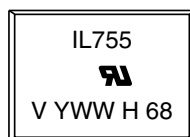
Fig. 10 - Test Circuit, Saturated and Non-Saturated Operation



PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (example)



Notes

- The VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.



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